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TL071, TL071A, TL071B, TL072
TL072A, TL072B, TL074, TL074A, TL074B
LOW-NOISE JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS080J − SEPTEMBER 1978 − REVISED MARCH 2005

- **Low Power Consumption**
- **Wide Common-Mode and Differential Voltage Ranges**
- **Low Input Bias and Offset Currents**
- **Output Short-Circuit Protection**
- **Low Total Harmonic Distortion . . . 0.003% Typ**
- **Low Noise**
  V_n = 18 nV/$\sqrt{Hz}$ Typ at f = 1 kHz
- **High Input Impedance . . . JFET Input Stage**
- **Internal Frequency Compensation**
- **Latch-Up-Free Operation**
- **High Slew Rate . . . 13 V/μs Typ**
- **Common-Mode Input Voltage Range Includes V_{CC+}**

description/ordering information

The JFET-input operational amplifiers in the TL07x series are similar to the TL08x series, with low input bias and offset currents and fast slew rate. The low harmonic distortion and low noise make the TL07x series ideally suited for high-fidelity and audio preamplifier applications. Each amplifier features JFET inputs (for high input impedance) coupled with bipolar output stages integrated on a single monolithic chip.

The C-suffix devices are characterized for operation from 0°C to 70°C. The I-suffix devices are characterized for operation from −40°C to 85°C. The M-suffix devices are characterized for operation over the full military temperature range of −55°C to 125°C.

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description/ordering information (continued)

ORDERING INFORMATION

T_A	V_{IO}max AT 25°C	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	10 mV	PDIP (P)	Tube of 50	TL071CP	TL071CP
			Tube of 50	TL072CP	TL072CP
		PDIP (N)	Tube of 25	TL074CN	TL074CN
		SOIC (D)	Tube of 75	TL071CD	TL071C
			Reel of 2500	TL071CDR	
			Tube of 75	TL072CD	TL072C
			Reel of 2500	TL072CDR	
			Tube of 50	TL074CD	TL074C
			Reel of 2500	TL074CDR	
		SOP (NS)	Reel of 2000	TL074CNSR	TL074
		SOP (PS)	Reel of 2000	TL071CPSR	TL071
			Reel of 2000	TL072CPSR	T072
		TSSOP (PW)	Reel of 2000	TL072CPWR	T072
			Tube of 90	TL074CPW	T074
			Reel of 2000	TL074CPWR	
	6 mV	PDIP (P)	Tube of 50	TL071ACP	TL071ACP
			Tube of 50	TL072ACP	TL072ACP
		PDIP (N)	Tube of 25	TL074ACN	TL074ACN
		SOIC (D)	Tube of 75	TL071ACD	071AC
			Reel of 2500	TL071ACDR	
			Tube of 75	TL072ACD	072AC
			Reel of 2500	TL072ACDR	
			Tube of 50	TL074ACD	TL074AC
			Reel of 2500	TL074ACDR	
		SOP (PS)	Reel of 2000	TL072ACPSR	T072A
		SOP (NS)	Reel of 2000	TL074ACNSR	TL074A
	3 mV	PDIP (P)	Tube of 50	TL071BCP	TL071BCP
			Tube of 50	TL072BCP	TL072BCP
		PDIP (N)	Tube of 25	TL074BCN	TL074BCN
		SOIC (D)	Tube of 75	TL071BCD	071BC
			Reel of 2500	TL071BCDR	
			Tube of 75	TL072BCD	072BC
			Reel of 2500	TL072BCDR	
			Tube of 50	TL074BCD	TL074BC
			Reel of 2500	TL074BCDR	
		SOP (NS)	Reel of 2000	TL074BCNSR	TL074B

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

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description/ordering information (continued)

ORDERING INFORMATION

T_A	V_{IO}max AT 25°C	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
−40°C to 85°C	6 mV	PDIP (P)	Tube of 50	TL071IP	TL071IP
			Tube of 50	TL072IP	TL072IP
		PDIP (N)	Tube of 25	TL074IN	TL074IN
		SOIC (D)	Tube of 75	TL071ID	TL071I
			Reel of 2500	TL071IDR	
			Tube of 75	TL072ID	TL072I
			Reel of 2500	TL072IDR	
			Tube of 50	TL074ID	TL074I
			Reel of 2500	TL074IDR	
−55°C to 125°C	6 mV	CDIP (JG)	Tube of 50	TL072MJGB	TL072MJGB
		CFP (U)	Tube of 150	TL072MUB	TL072MUB
		LCCC (FK)	Tube of 55	TL072MFKB	TL072MFKB
	9 mV	CDIP (J)	Tube of 25	TL074MJB	TL074MJB
		CFP (W)	Tube of 25	TL074MWB	TL074MWB
		LCCC (FK)	Tube of 55	TL074MFKB	TL074MFKB

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

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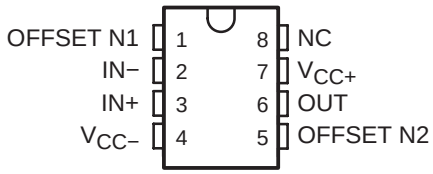
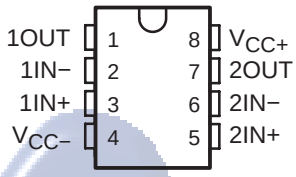
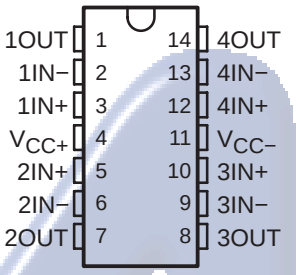
TL071, TL071A, TL071B
D, P, OR PS PACKAGE
(TOP VIEW)



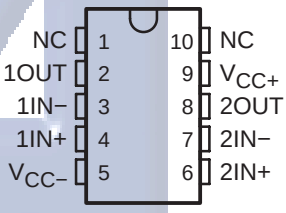
TL072, TL072A, TL072B
D, JG, P, PS, OR PW PACKAGE
(TOP VIEW)



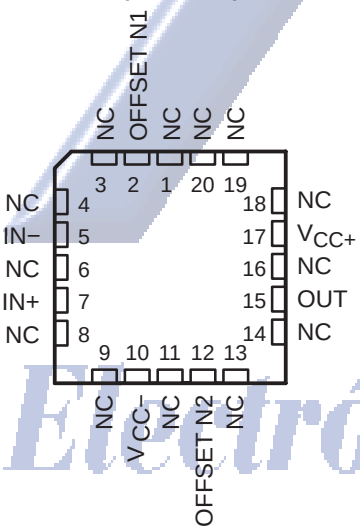
TL074A, TL074B
D, J, N, NS, OR PW PACKAGE
TL074 . . . D, J, N, NS, PW,
OR W PACKAGE
(TOP VIEW)



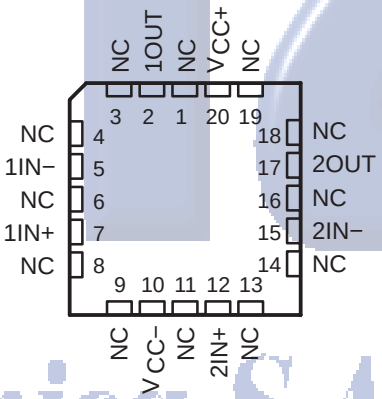
TL072
U PACKAGE
(TOP VIEW)



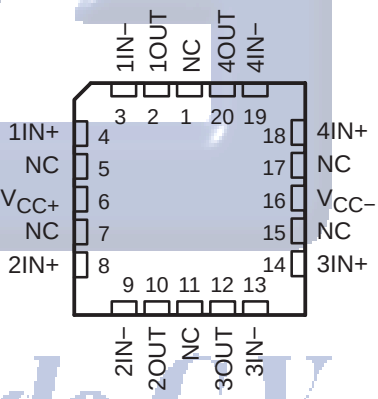
TL071
FK PACKAGE
(TOP VIEW)



TL072
FK PACKAGE
(TOP VIEW)



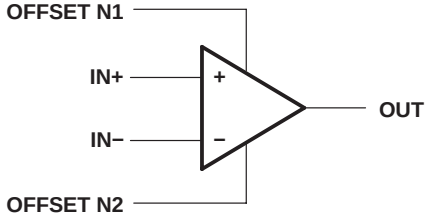
TL074
FK PACKAGE
(TOP VIEW)



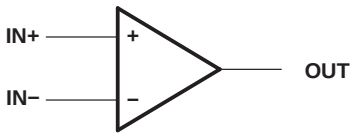
NC − No internal connection

symbols

TL071



TL072 (each amplifier)
TL074 (each amplifier)



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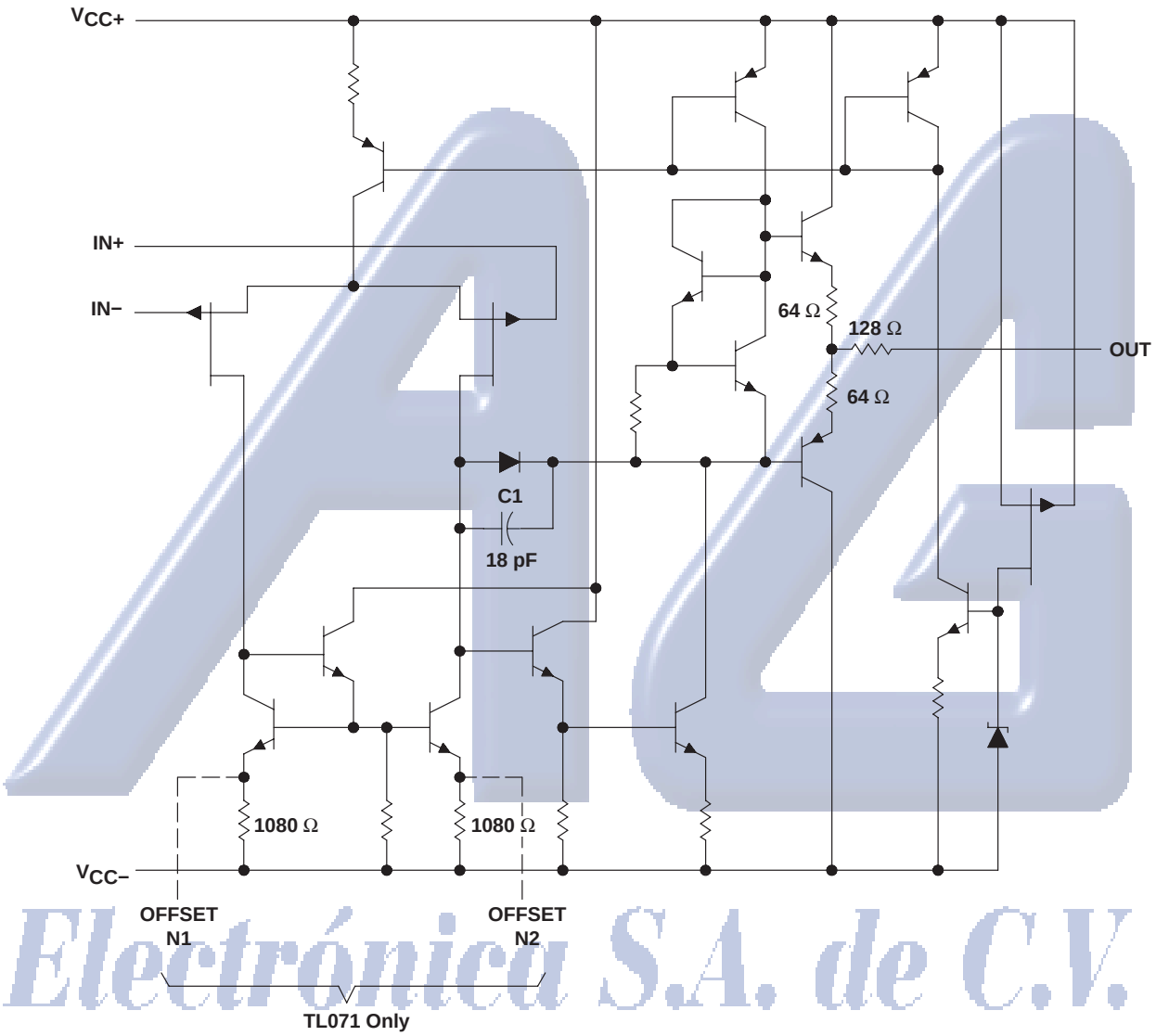
schematic (each amplifier)



All component values shown are nominal.

COMPONENT COUNT†			
COMPONENT TYPE	TL071	TL072	TL074
Resistors	11	22	44
Transistors	14	28	56
JFET	2	4	6
Diodes	1	2	4
Capacitors	1	2	4
epi-FET	1	2	4

† Includes bias and trim circuitry

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage (see Note 1):	V_{CC+}	18 V
	V_{CC-}	−18 V
Differential input voltage, V_{ID} (see Note 2)		±30 V
Input voltage, V_I (see Notes 1 and 3)		±15 V
Duration of output short circuit (see Note 4)		Unlimited
Package thermal impedance, θ_{JA} (see Notes 5 and 6):	D package (8 pin)	97°C/W
	D package (14 pin)	86°C/W
	N package	80°C/W
	NS package	76°C/W
	P package	85°C/W
	PS package	95°C/W
	PW package (8 pin)	149°C/W
	PW package (14 pin)	113°C/W
	U package	185°C/W
Package thermal impedance, θ_{JC} (see Notes 7 and 8):	FK package	5.61°C/W
	J package	15.05°C/W
	JG package	14.5°C/W
	W package	14.65°C/W
Operating virtual junction temperature, T_J		150°C
Case temperature for 60 seconds: FK package		260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: J, JG, or W package		300°C
Storage temperature range, T_{stg}		−65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
2. Differential voltages are at IN+, with respect to IN−.
3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
5. Maximum power dissipation is a function of $T_J(max)$, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
6. The package thermal impedance is calculated in accordance with JESD 51-7.
7. Maximum power dissipation is a function of $T_J(max)$, θ_{JC}, and T_C. The maximum allowable power dissipation at any allowable case temperature is $P_D = (T_J(max) - T_C)/\theta_{JC}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
8. The package thermal impedance is calculated in accordance with MIL-STD-883.

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electrical characteristics, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	T_A‡	TL071C TL072C TL074C			TL071AC TL072AC TL074AC			TL071BC TL072BC TL074BC			TL071I TL072I TL074I			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_O = 0, R_S = 50 Ω	25°C		3	10		3	6		2	3		3	6	mV
			Full range			13			7.5			5			8	
α_{VIO}	Temperature coefficient of input offset voltage	V_O = 0, R_S = 50 Ω	Full range		18			18			18			18		µV/°C
I_{IO}	Input offset current	V_O = 0	25°C		5	100		5	100		5	100		5	100	pA
			Full range			10			2			2			2	nA
I_{IB}	Input bias current§	V_O = 0	25°C		65	200		65	200		65	200		65	200	pA
			Full range			7			7			7			20	nA
V_{ICR}	Common-mode input voltage range		25°C	±11	−12 to 15		±11	−12 to 15		±11	−12 to 15		±11	−12 to 15		V
V_{OM}	Maximum peak output voltage swing	R_L = 10 kΩ	25°C	±12	±13.5		±12	±13.5		±12	±13.5		±12	±13.5		V
		R_L ≥ 10 kΩ	Full range	±12			±12			±12			±12			
		R_L ≥ 2 kΩ		±10			±10			±10			±10			
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V, R_L ≥ 2 kΩ	25°C	25	200		50	200		50	200		50	200		V/mV
			Full range	15			25			25			25			
B_1	Unity-gain bandwidth		25°C		3			3			3			3		MHz
r_i	Input resistance		25°C		10^{12}			10^{12}			10^{12}			10^{12}		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω	25°C	70	100		75	100		75	100		75	100		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	V_{CC} = ±9 V to ±15 V, V_O = 0, R_S = 50 Ω	25°C	70	100		80	100		80	100		80	100		dB
I_{CC}	Supply current (each amplifier)	V_O = 0, No load	25°C		1.4	2.5		1.4	2.5		1.4	2.5		1.4	2.5	mA
V_{O1}/V_{O2}	Crosstalk attenuation	A_{VD} = 100	25°C		120			120			120			120		dB

† All characteristics are measured under open-loop conditions with zero common-mode voltage, unless otherwise specified.
‡ Full range is T_A = 0°C to 70°C for TL07_C,TL07_AC, TL07_BC and is T_A = −40°C to 85°C for TL07_I.
§ Input bias currents of an FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive, as shown in Figure 4. Pulse techniques must be used that maintain the junction temperature as close to the ambient temperature as possible.

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electrical characteristics, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	T_A‡	TL071M TL072M			TL074M			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_O = 0, R_S = 50 Ω	25°C		3	6		3	9	mV
			Full range			9			15	
α_{VIO}	Temperature coefficient of input offset voltage	V_O = 0, R_S = 50 Ω	Full range		18			18		μV/°C
I_{IO}	Input offset current	V_O = 0	25°C		5	100		5	100	pA
			Full range			20			20	nA
I_{IB}	Input bias current‡	V_O = 0	25°C		65	200		65	200	pA
						50			50	nA
V_{ICR}	Common-mode input voltage range		25°C	±11	−12 to 15		±11	−12 to 15		V
V_{OM}	Maximum peak output voltage swing	R_L = 10 kΩ	25°C	±12	±13.5		±12	±13.5		V
		R_L ≥ 10 kΩ	Full range	±12			±12			
		R_L ≥ 2 kΩ		±10			±10			
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V, R_L ≥ 2 kΩ	25°C	35	200		35	200		V/mV
				15			15			
B_1	Unity-gain bandwidth	T_A = 25°C			3			3		MHz
r_i	Input resistance	T_A = 25°C			10^{12}			10^{12}		Ω
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0, R_S = 50 Ω	25°C	80	86		80	86		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	V_{CC} = ±9 V to ±15 V, V_O = 0, R_S = 50 Ω	25°C	80	86		80	86		dB
I_{CC}	Supply current (each amplifier)	V_O = 0, No load	25°C		1.4	2.5		1.4	2.5	mA
V_{O1}/V_{O2}	Crosstalk attenuation	A_{VD} = 100	25°C		120			120		dB

† Input bias currents of an FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive, as shown in Figure 4. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

‡ All characteristics are measured under open-loop conditions with zero common-mode voltage, unless otherwise specified. Full range is T_A = −55°C to 125°C.

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operating characteristics, $V_{CC\pm}$ = ±15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TL07xM			ALL OTHERS			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V_I = 10 V, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1	5	13		8	13		V/μs
t_r	Rise-time overshoot factor	V_I = 20 mV, C_L = 100 pF,	R_L = 2 kΩ, See Figure 1		0.1			0.1		μs
					20%			20%		
V_n	Equivalent input noise voltage	R_S = 20 Ω	f = 1 kHz		18			18		nV/√Hz
			f = 10 Hz to 10 kHz		4			4		μV
I_n	Equivalent input noise current	R_S = 20 Ω,	f = 1 kHz		0.01			0.01		pA/√Hz
THD	Total harmonic distortion	$V_I$rms = 6 V, R_L ≥ 2 kΩ, f = 1 kHz	A_{VD} = 1, R_S ≤ 1 kΩ,		0.003 %			0.003%		

PARAMETER MEASUREMENT INFORMATION

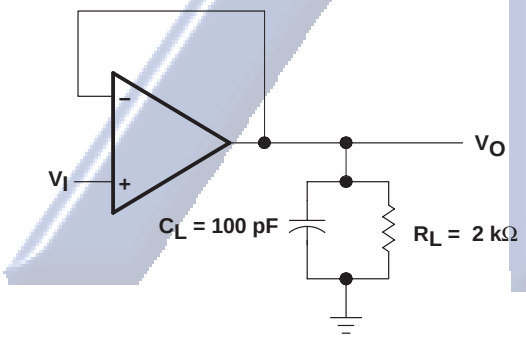

Figure 1. Unity-Gain Amplifier

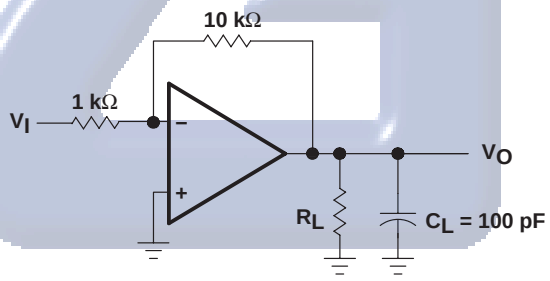

Figure 2. Gain-of-10 Inverting Amplifier

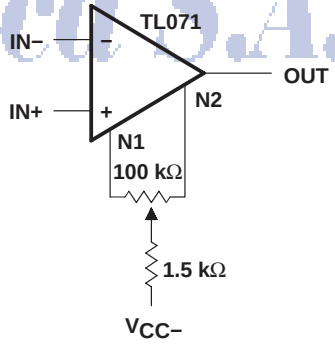

Figure 3. Input Offset-Voltage Null Circuit

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TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
I_{IB}	Input bias current	vs Free-air temperature	4
V_{OM}	Maximum output voltage	vs Frequency vs Free-air temperature vs Load resistance vs Supply voltage	5, 6, 7 8 9 10
A_{VD}	Large-signal differential voltage amplification	vs Free-air temperature vs Frequency	11 12
	Phase shift	vs Frequency	12
	Normalized unity-gain bandwidth	vs Free-air temperature	13
	Normalized phase shift	vs Free-air temperature	13
CMRR	Common-mode rejection ratio	vs Free-air temperature	14
I_{CC}	Supply current	vs Supply voltage vs Free-air temperature	15 16
P_D	Total power dissipation	vs Free-air temperature	17
	Normalized slew rate	vs Free-air temperature	18
V_n	Equivalent input noise voltage	vs Frequency	19
THD	Total harmonic distortion	vs Frequency	20
	Large-signal pulse response	vs Time	21
V_O	Output voltage	vs Elapsed time	22

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TYPICAL CHARACTERISTICS†

INPUT BIAS CURRENT
vs
FREE-AIR TEMPERATURE

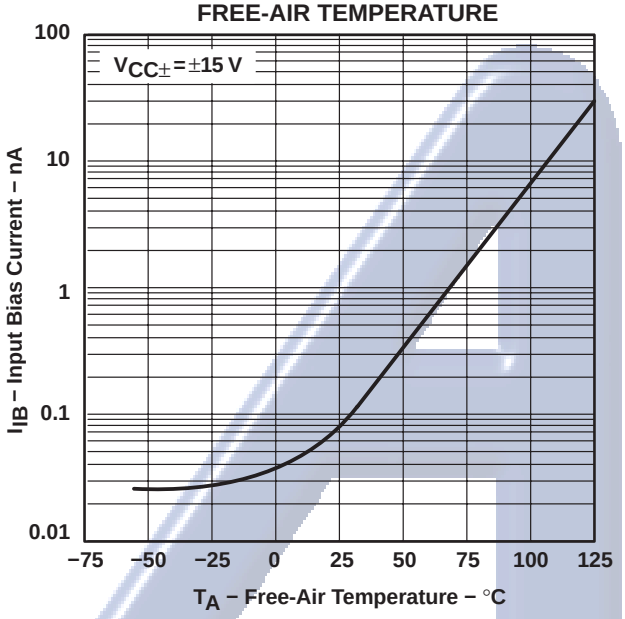

Figure 4

MAXIMUM PEAK OUTPUT VOLTAGE
vs
FREQUENCY

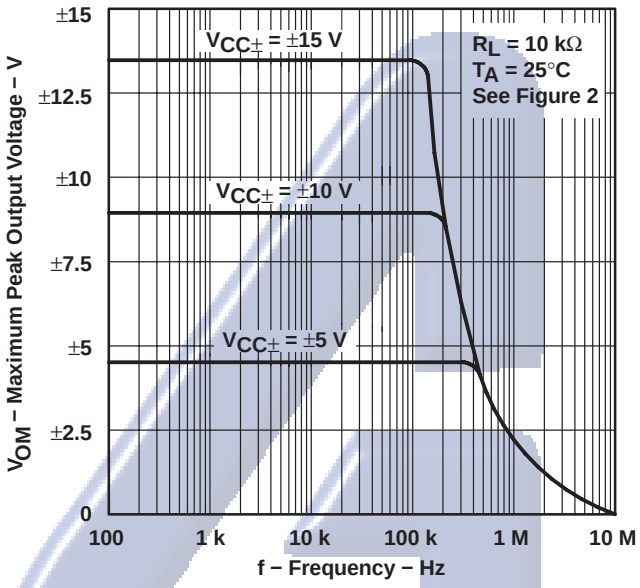

Figure 5

MAXIMUM PEAK OUTPUT VOLTAGE
vs
FREQUENCY

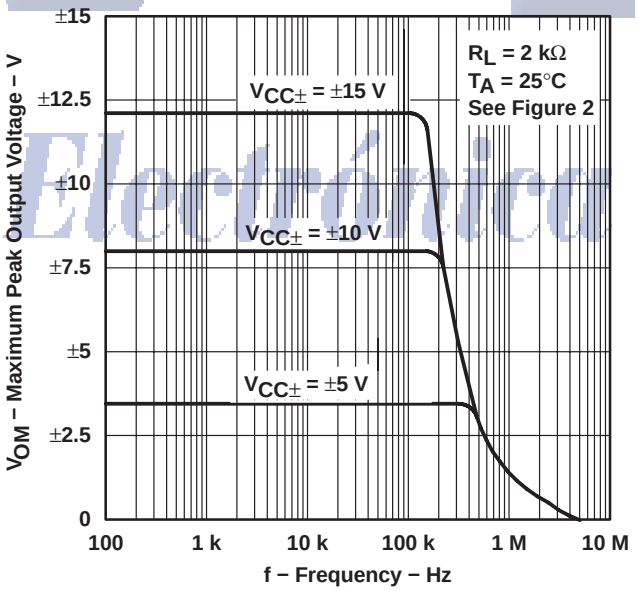

Figure 6

MAXIMUM PEAK OUTPUT VOLTAGE
vs
FREQUENCY

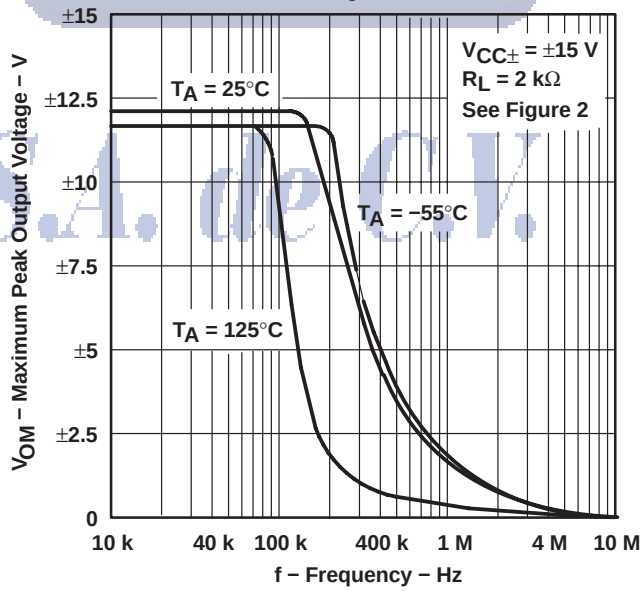

Figure 7

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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